L Number	Hits	Search Text	DB	Time stamp
37	4967	((penetrat$3 permeable permeat$3 diffus$4) with (pattern$4 etch$3) with (dielectric insulat$3)) and (cathode electrode)	USPAT; US-PGPUB	2004/10/16 15:41
38	2454	((penetrat$3 permeable permeat$3 diffus$4) with (pattern$4 etch$3) with (dielectric insulat$3)) same (cathode electrode)	USPAT; US-PGPUB	2004/10/16 15:41
51	25	(((penetrat$3 permeable permeat$3 diffus$4) with (pattern$4 etch$3) with (dielectric insulat$3)) same (cathode electrode)) and 156/$.ccls.	USPAT; US-PGPUB	2004/10/16 15:46
52	1081	(((penetrat$3 permeable permeat$3 diffus$4) with (pattern$4 etch$3) with (dielectric insulat$3)) same (cathode electrode))	EPO; JPO; DERWENT	2004/10/16 15:46
53	15	(((penetrat$3 permeable permeat$3 diffus$4) with (pattern$4 etch$3) with (thick near3 (dielectric insulat$3))) same (cathode electrode))	EPO; JPO; DERWENT	2004/10/16 15:50
54	1	5047313.pn.	USPAT; US-PGPUB	2004/10/16 15:54
55	0	(multil$layer$3 near3 cathode) and (dielectric insulat$3)	USPAT; US-PGPUB	2004/10/16 15:55
56	801	(multi$layer$3 with cathode) and (dielectric insulat$3)	USPAT; US-PGPUB	2004/10/16 15:55
57	203	(multi$layer$3 near3 cathode) and (dielectric insulat$3)	USPAT; US-PGPUB	2004/10/16 15:55
58	67	(multi$layer$3 near3 cathode) and (dielectric insulat$3) and (313/$.ccls.)	USPAT; US-PGPUB	2004/10/16 15:59
59	7	(multi$layer$3 near3 cathode) and (thick near3 (dielectric insulat$3 isolat$3)) and (313/$.ccls.)	USPAT; US-PGPUB	2004/10/16 16:00
60	333	((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (313/$.ccls.)	USPAT; US-PGPUB	2004/10/16 16:40
61	82	(((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric) same pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (313/$.ccls.)	USPAT; US-PGPUB	2004/10/16 17:11
62	22	("3731131" | "3998678" | "4193013" | "4345181" | "4498952" | "4551649" | "4683399" | "5019003" | "5129850" | "5138220" | "5141460" | "5180951" | "5190796" | "5199918" | "5202571" | "5227699" | "5249340" | "5252833" | "5278475" | "5371431" | "5449970" | "5451830").PN.	USPAT	2004/10/16 16:45
63	4	(((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric) same pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	EPO; JPO; DERWENT	2004/10/16 17:08
64	46	(((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric)) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	EPO; JPO; DERWENT	2004/10/16 17:08
65	3	(((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric) same pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (216/$.ccls.)	USPAT; US-PGPUB	2004/10/16 17:13
66	62	(((thick near3 (dielectric insulat$3 isolat$3)) thick$dielectric) with pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/16 17:21
67	4	("3970887" | "4513308" | "5266530" | "5358908").PN.	USPAT	2004/10/16 17:13
68	3584	((dielectric insulat$3 isolat$3) with pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/16 17:22
69	88	((dielectric insulat$3 isolat$3) with pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (216/$.ccls.)	USPAT; US-PGPUB	2004/10/16 19:24
70	19	((dielectric insulat$3 isolat$3) with thick with pattern$3) and (216/13,17,62,87,95.ccls.)	USPAT; US-PGPUB	2004/10/16 19:25
71	19	((dielectric insulat$3 isolat$3) with thick) and (216/62.ccls.)	USPAT; US-PGPUB	2004/10/16 19:26
72	151	((dielectric insulat$3 isolat$3)) and (216/62.ccls.)	USPAT; US-PGPUB	2004/10/16 19:26
73	91	((dielectric insulat$3 isolat$3)) and (cathode electrode conductor) and (216/62.ccls.)	USPAT; US-PGPUB	2004/10/16 19:33

-	1371	((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode)	USPAT; US-PGPUB	2004/07/20 11:18
-	5	((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 445/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:19
-	20	((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 430/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:21
-	31	((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 216/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:24
-	49	((((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 430/$.ccls.) (((diffus$3 near3 (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 216/$.ccls.)	USPAT; US-PGPUB	2004/07/20 11:21
-	113	((diffus$3 with (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and 216/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:24
-	198	((diffus$3 with (pattern$3 etch$3)) same (insulat$3 dielectric)) and (cathode electrode) and (216/$.ccls. 430/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/07/20 11:24
-	128	(diffus$3 with (pattern$3 etch$3) with (insulat$3 dielectric)) and (cathode electrode) and (216/$.ccls. 430/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/07/20 11:50
-	42	(actinic near3 (radiat$3)) and 445/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:51
-	42	(actinic near3 (radiat$3)) and 445/$.ccls.	USPAT; US-PGPUB	2004/07/20 11:51
-	2	(actinic near3 (radiat$3)) and 445/$.ccls.	USOCR	2004/07/20 11:51
-	13	((actinic near3 (radiat$3)) same (dielectric insulat$3)) and 445/$.ccls.	USPAT; US-PGPUB	2004/07/20 13:35
-	112	((actinic near3 (radiat$3)) same (dielectric insulat$3)) and (438/$.ccls. 216/$.ccls. 430/$.ccls 445/$.ccls.)	USPAT; US-PGPUB	2004/07/20 13:36
-	140	((actinic near3 (radiat$3 irradiat$3 expos$3 develop$4)) same (dielectric insulat$3)) and (438/$.ccls. 216/$.ccls. 430/$.ccls 445/$.ccls.)	USPAT; US-PGPUB	2004/07/20 13:37
-	66	((actinic near3 (radiat$3 irradiat$3 expos$3 develop$4)) same (dielectric insulat$3)) and (438/$.ccls. 216/$.ccls. 430/$.ccls 445/$.ccls.) and (cathode electrode)	USPAT; US-PGPUB	2004/07/20 13:38
-	16	(actinic with (radiat$3 irradiat$3 expos$3 develop$4) with (dielectric insulat$3)) and (438/$.ccls. 216/$.ccls. 430/$.ccls 445/$.ccls.) and (cathode electrode)	USPAT; US-PGPUB	2004/07/20 16:01
-	10	(actinic with (radiat$3 irradiat$3 expos$3 develop$4) with (dielectric insulat$3)) and (313/$.ccls.) and (cathode electrode)	USPAT; US-PGPUB	2004/07/20 15:53
-	20	(actinic with (radiat$3 irradiat$3 expos$3 develop$4) with (dielectric insulat$3)) and (cathode electrode) and ((field electron) near3 (emitter source emission emitting emissive))	USPAT; US-PGPUB	2004/07/20 16:12
-	2	(actinic same (radiat$3 irradiat$3 expos$3 develop$4) same (dielectric insulat$3)) and (cathode electrode) and ((field electron) near3 (emitter source emission emitting emissive))	EPO; JPO; DERWENT	2004/07/20 16:12
-	1	1998-532288.NRAN.	DERWENT	2004/07/20 16:12
-	249	((diffusion with pattern$3) same (dielectric insulat$3)) and ((field electron) near3 (emisison source emissive emitting))	USPAT; US-PGPUB	2004/07/22 15:44
-	699	((diffusion same pattern$3) same (dielectric insulat$3)) and ((field electron) near3 (emisison source emissive emitting))	USPAT; US-PGPUB	2004/07/22 15:44
-	0	(diffus$4 same (remov$3 pattern$3) same actinic same (dielectric insulat$3)) and ((field electron) near3 (emisison source emissive emitting) near3 (display device panel))	USPAT; US-PGPUB	2004/07/22 15:47
-	2	(diffus$4 same (remov$3 pattern$3) same actinic same (dielectric insulat$3)) and ((field electron) near3 (emisison source emissive emitting))	USPAT; US-PGPUB	2004/07/22 15:47
-	62	((difus$3patern$3 (diffus$3 near3 pattern$3)) same (insualat$3 dielectric isolat$3)) and (FED ((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:03
-	702	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (FED ((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:03

-	23	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter))) and (445/$.ccls. 313/$.ccls. 430/$.ccls.)	USPAT; US-PGPUB	2004/10/08 14:20
-	1	5032216.pn.	USPAT; US-PGPUB	2004/10/08 14:15
-	4	5209814.pn. 5260163.pn. 5275689.pn. 5306756.pn.	USPAT; US-PGPUB	2004/10/08 14:16
-	455	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:36
-	7	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter))) and 216/$.ccls.	USPAT; US-PGPUB	2004/10/08 14:43
-	0	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter))) and 524/$.ccls.	USPAT; US-PGPUB	2004/10/08 14:42
-	1658	((difus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (electrode cathode) and (430/$.ccls. 445/$.ccls. 313/$.ccls. 438/$.ccls. 216/$.ccls.)	USPAT; US-PGPUB	2004/10/08 14:43
-	455	((diffus$3patern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:44
-	455	((diffus$3pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:44
-	455	((diffus$pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 14:45
-	14	((diffus$pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (((electron field) near3 (source emitting emission emissive emitter)))	EPO; JPO; DERWENT	2004/10/08 14:58
-	22	((diffus$pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (electrdoe cathode anode)	EPO; JPO; DERWENT	2004/10/08 15:03
-	766	((diffus$pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/10/08 15:03
-	763	((diffus$pattern$3 (diffus$3 with pattern$3)) same (insulat$3 dielectric isolat$3)) and (electrode cathode)	EPO; JPO; DERWENT	2004/10/08 15:04
-	471	((diffus$pattern$3 (diffus$3 with pattern$3)) with (insulat$3 dielectric isolat$3)) and (electrode cathode)	EPO; JPO; DERWENT	2004/10/08 15:05
-	6	((diffus$pattern$3 (diffus$3 with pattern$3)) with (insulat$3 dielectric isolat$3)) and (cathode)	EPO; JPO; DERWENT	2004/10/08 15:07
-	228	((diffus$pattern$3 (diffus$3 with pattern$3)) with (insulat$3 dielectric isolat$3)) and (cathode)	USPAT; US-PGPUB	2004/10/08 15:08
-	2	((diffus$pattern$3 (diffus$3 with pattern$3)) with paste with (insulat$3 dielectric isolat$3)) and (cathode)	USPAT; US-PGPUB	2004/10/08 15:53
-	3	("5032216" | "5209814" | "5275689").PN.	USPAT	2004/10/08 15:20
-	5	5385631.URPN.	USPAT	2004/10/08 15:21
-	4	("5032216" | "5037723" | "5136207" | "5385631").PN.	USPAT	2004/10/08 15:22
-	5	5385631.URPN.	USPAT	2004/10/08 15:50
-	4	5635334.URPN.	USPAT	2004/10/08 15:50
-	4	("5032216" | "5037723" | "5136207" | "5385631").PN.	USPAT	2004/10/08 15:51
-	13	((diffus$pattern$3 (diffus$3 with pattern$3)) with paste with (insulat$3 dielectric isolat$3)) and (cathode electrode)	USPAT; US-PGPUB	2004/10/08 15:54
-	74	(pattern$3 with thick with (dielectric insulat$3 isolat$3)) and (cathode electrode) and (((electron field) near3 (source emitting emission emissive emitter))) and (313/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/10/08 16:03
-	32	(pattern$3 with (thick near3 (dielectric insulat$3 isolat$3))) and (cathode electrode) and (((electron field) near3 (source emitting emission emissive emitter))) and (313/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/10/08 16:08
-	372	((thick near3 (dielectric insulat$3 isolat$3))) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (313/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/10/08 16:13

-	66	(((thick near3 (dielectric insulat$3 isolat$3))) same (conventional known)) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (313/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/10/08 16:27
-	0	(thick$dielectric same (conventional known)) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter))) and (313/$.ccls. 445/$.ccls.)	USPAT; US-PGPUB	2004/10/08 16:28
-	0	(thick$dielectric) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/16 16:00
-	0	(thick$dielectric) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	EPO; JPO; DERWENT	2004/10/08 16:28
-	9	(thick near3 dielectric) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	EPO; JPO; DERWENT	2004/10/08 16:31
-	72	((thick near3 dielectric) same pattern$3) and (cathode electrode) and (((electron field) near3 (emitting emission emissive emitter)))	USPAT; US-PGPUB	2004/10/08 16:32